onsemi

MARKING

TinyLogic HST Inverter NC7ST04

Description

The NC7ST04 is a single high performance CMOS Inverter, with TTL-compatible inputs. Advanced Silicon Gate CMOS fabrication assures high speed and low power circuit operation. ESD protection diodes inherently guard both input and output with respect to the V_{CC} and GND rails. High gain circuitry offers high noise immunity and reduced sensitivity to input edge rate. The TTL-compatible input facilitates TTL to NMOS/CMOS interfacing. Device performance is similar to MM74HCT but with 1/2 the output current drive of HC/HCT.

Features

- Space Saving SOT23-5, SC-74A and SC-88A 5-Lead Packages
- High Speed; $t_{PD} < 7$ ns typ, $V_{CC} = 5$ V, $C_L = 15$ pF
- Low Quiescent Power; $I_{CC} < 1 \mu A$ typ, $V_{CC} = 5.5 V$
- Balanced Output Drive; 2 mA I_{OL}, -2 mA I_{OH}
- TTL-compatible Inputs
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

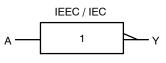


Figure 1. Logic Symbol

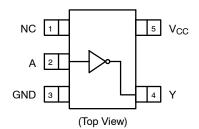
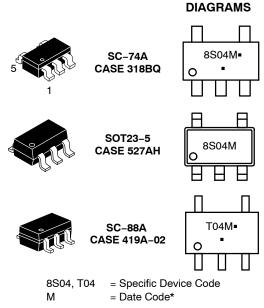


Figure 2. Connection Diagram



*Date Code orientation and/or position may vary depending upon manufacturing location.

PIN ASSIGNMENT

Pin Name	Description
А	Input
Y	Output
NC	No Connect

FUNCTION TABLE $(Y = \overline{A})$

Input	Output
Α	Y
L	Н
Н	L

H = HIGH Logic Level

L = LOW Logic Level

ORDERING INFORMATION

See detailed ordering, marking and shipping information in the package dimensions section on page 3 of this data sheet.

NC7ST04

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter		Min	Max	Unit
V _{CC}	Supply Voltage		-0.5	6.5	V
I _{IK}	DC Input Diode Current	V _{IN} < 0 V	_	-20	mA
		$V_{IN} > V_{CC}$	_	+20	
V _{IN}	DC Input Voltage		-0.5	V _{CC} + 0.5 V	V
I _{OK}	DC Output Diode Current V _{OUT} < 0 V		_	-20	mA
	V _{OUT} > V _{CC}	_	+20		
V _{OUT}	DC Output Voltage		-0.5	V _{CC} + 0.5 V	V
I _{OUT}	DC Output Source or Sink Currer	ıt	_	±12.5	mA
$I_{CC} \text{ or } I_{GND}$	DC V _{CC} or Ground Current per S	upply Pin	_	±25	mA
T _{STG}	Storage Temperature Range		-65	+150	°C
TJ	Junction Temperature		_	150	°C
	DC V _{CC} or Ground Current per (S	Soldering, 10 Seconds)	_	+260	°C
PD	Power Dissipation in Still Air	SC-74A / SOT23-5	_	390	mW
		SC-88A	-	332	1

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Conditions	Min	Мах	Unit
V _{CC}	Supply Voltage		4.5	5.5	V
V _{IN}	Input Voltage		0	V _{CC}	V
V _{OUT}	Output Voltage		0	V _{CC}	V
T _A	Operating Temperature		-40	+85	°C
t _r , t _f	Input Rise and Fall Times	V _{CC} = 5.0 V	0	10	ns/V
θ_{JA}	Thermal Resistance	SC-74A / SOT23-5	-	320	°C/W
		SC-88A	-	377	

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

1. Unused inputs must be held HIGH or LOW. They may not float.

DC ELECTICAL CHARACTERISTICS

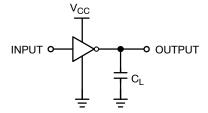
				T,	_A = +25°	С	T _A = -40	to +85°C	
Symbol	Parameter	V _{CC} (V)	Conditions	Min	Тур	Max	Min	Max	Unit
V _{IH}	HIGH Level Input Voltage	4.5 – 5.5		2.0	-	-	2.0	-	V
V _{IL}	LOW Level Input Voltage	4.5 – 5.5		-	-	0.8	-	0.8	V
V _{OH}	HIGH Level Output Voltage	4.5	$I_{OH} = -20 \ \mu A$,	4.4	4.5	-	4.4	-	V
	vollage	4.5	$V_{IN} = V_{IH} \text{ or } V_{IL},$ $I_{OH} = -2 \text{ mA}$	4.18	4.35	-	4.13	-	
V _{OL}	LOW Level Output Voltage	4.5	$I_{OL} = 20 \ \mu A,$	-	0	0.1	-	0.1	V
	vollage	4.5	V _{IN} = V _{IH} or V _{IL} , I _{OL} = 2 mA	-	0.10	0.26	-	0.33	
I _{IN}	Input Leakage Current	5.5	$0 \leq V_{IN} \leq 5.5 \text{ V}$	-	-	±0.1	-	±1.0	μA
I _{CC}	Quiescent Supply Current	5.5	$V_{IN} = V_{CC}$ or GND	-	-	1.0	-	10.0	μA
I _{CCT}	I _{CC} per Input	5.5	Input V_{IN} = 0.5 V or 2.4 V	-	-	2.0	-	2.9	mA

AC ELECTRICAL CHARACTERISTICS

					T _A = 25°C		$T_A = -40$) to 85°C	
Symbol	Parameter	V _{CC} (V)	Conditions	Min	Тур	Max	Min	Max	Unit
t _{PLH} , t _{PHL}	Propagation Delay	5.0	C _L = 15 pF	-	3.5	12	-	-	ns
	(Figure 3, 5)			-	6.0	17	-	-	
		4.5	C _L = 50 pF	-	6.2	16	-	20	
				-	11.4	27	-	31	
		5.5		-	4.3	14	-	18	
				-	11.1	26	-	30	
t_{TLH}, t_{THL}	Output Transition Time	5.0	C _L = 15 pF	-	4	10	-	-	ns
	(Figure 3, 5)	4.5	C _L = 50 pF	-	11	25	-	31	
		5.5		-	10	21	-	26	
C _{IN}	Input Capacitance	Open		-	2	10	-	-	pF
C _{PD}	Power Dissipation Capacitance (Figure 4)	5.00	(Note 2)	_	6	-	-	-	pF

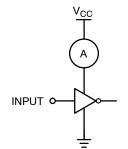
2. C_{PD} is defined as the value of the internal equivalent capacitance which is derived from dynamic operating current consumption (I_{CCD}) at no output lading and operating at 50% duty cycle. C_{PD} is related to I_{CCD} dynamic operating current by the expression: I_{CCD} = (C_{PD}) (V_{CC}) (f_{IN}) + (I_{CCStatic}).

AC Loading and Waveforms



 C_L includes load and stray capacitance; inputs PRR = 1.0 MHz, t_W = 500 ns.





Input = AC Waveform; PRR = Variable; Duty Cycle = 50%.

Figure 4. I_{CCD} Test Circuit

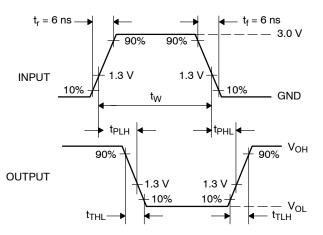


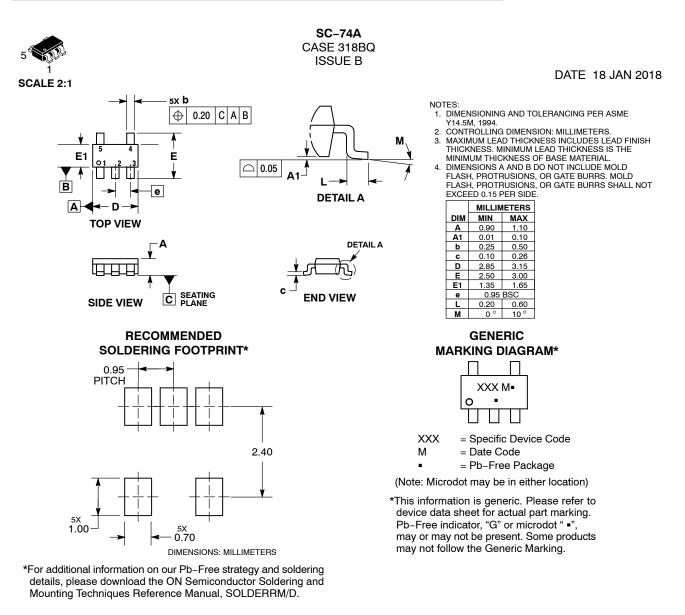
Figure 5. AC Waveforms

DEVICE ORDERING INFORMATION

Device	Top Mark	Packages	Shipping [†]
NC7ST04M5X	8S04	SC-74A	3000 / Tape & Reel
NC7ST04M5X-L22090	8S04	SOT23-5	3000 / Tape & Reel
NC7ST04P5X	T04	SC-88A	3000 / Tape & Reel
NC7ST04P5X-L22057	T04	SC-88A	3000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.





DOCUMENT NUMBER:	98AON66279G	Electronic versions are uncontrolled except when accessed directly from Printed versions are uncontrolled except when stamped "CONTROLLED 0					
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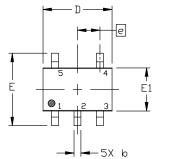
SC-88A (SC-70-5/SOT-353) CASE 419A-02 **ISSUE M**

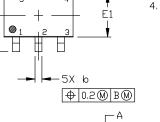
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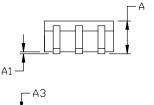
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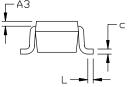
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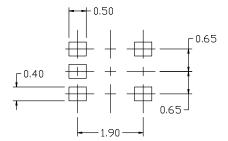
DATE 11 APR 2023











RECOMMENDED MOUNTING FOOTPRINT

For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.

DIM	MILLIMETERS			
MIU	MIN.	NDM.	MAX.	
A	0.80	0.95	1.10	
A1			0.10	
A3	0.20 REF			
b	0.10	0.20	0.30	
С	0.10		0.25	
D	1.80	2.00	5'50	
E	2.00	2.10	5'50	
E1	1.15	1.25	1.35	
e		0.65 BSI	С	
L	0.10	0.15	0.30	

DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH,

PROTRUSIONS, OR GATE BURRS.MOLD FLASH, PROTRUSIONS,

OR GATE BURRS SHALL NOT EXCEED 0.1016MM PER SIDE.

CONTROLLING DIMENSION: MILLIMETERS 419A-01 DBSOLETE, NEW STANDARD 419A-02

GENERIC MARKING





*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

XXX = Specific Device Code

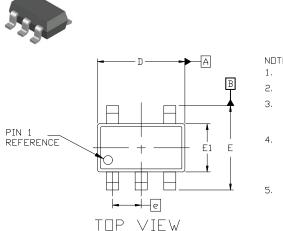
Μ = Date Code = Pb-Free Package

(Note: Microdot may be in either location)

STYLE 1: PIN 1. BASE 2. EMITTER 3. BASE 4. COLLECTOR 5. COLLECTOR	STYLE 2: PIN 1. ANODE 2. EMITTER 3. BASE 4. COLLECTOR 5. CATHODE	STYLE 3: PIN 1. ANODE 1 2. N/C 3. ANODE 2 4. CATHODE 2 5. CATHODE 1	STYLE 4: PIN 1. SOURCE 1 2. DRAIN 1/2 3. SOURCE 1 4. GATE 1 5. GATE 2	STYLE 5: PIN 1. CATHODE 2. COMMON ANOD 3. CATHODE 2 4. CATHODE 3 5. CATHODE 4	E
STYLE 6: PIN 1. EMITTER 2 2. BASE 2 3. EMITTER 1 4. COLLECTOR 5. COLLECTOR 2/BASE	STYLE 7: PIN 1. BASE 2. EMITTER 3. BASE 4. COLLECTOR 1 5. COLLECTOR	STYLE 8: PIN 1. CATHODE 2. COLLECTOR 3. N/C 4. BASE 5. EMITTER	STYLE 9: PIN 1. ANODE 2. CATHODE 3. ANODE 4. ANODE 5. ANODE	Note: Please refer to style callout. If style to out in the datasheet r datasheet pinout or p	ype is not called efer to the device
DOCUMENT NUMBER:	98ASB42984B			ot when accessed directly from when stamped "CONTROLLED (
DESCRIPTION:	DESCRIPTION: SC-88A (SC-70-5/SOT-353)				PAGE 1 OF 1

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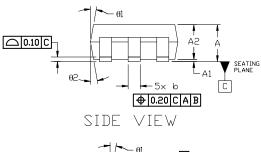


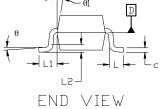
SOT-23, 5 Lead CASE 527AH **ISSUE A**

DATE 09 JUN 2021

NDTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 19894
- CONTROLLING DIMENSION: MILLIMETERS
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL
- DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.25 PER SIDE. D AND E1 DIMENSIONS ARE DETERMINED AT DATUM D.
- DIMENSION 'b' DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08mm TOTAL IN EXCESS OF THE 'b' DIMENSION AT MAXIMUM MATERIAL CONDITION. MINIMUM SPACE BETWEEN PROTRUSION AND AN ADJACENT LEAD SHALL NOT BE LESS THAN 0.07mm.





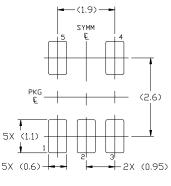
GENERIC **MARKING DIAGRAM***



XXX = Specific Device Code = Date Code М

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

	MILLIMETERS			
DIM	MIN.	NDM.	MAX.	
Α	0.90	—	1.45	
A1	0.00	—	0.15	
A2	0.90	1.15	1.30	
b	0.30	—	0.50	
С	0.08	_	0.22	
D	2.90 BSC			
E	2.80 BSC			
E1	1.60 BSC			
е	0	.95 BSC		
L	0.30	0.45	0.60	
L1	0.60 REF			
L2	0.25 REF			
θ	0*	4°	8*	
01	0*	10°	15°	
θ 2	0°	10°	15°	



RECOMMENDED MOUNTING FOOTPRINT

For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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